



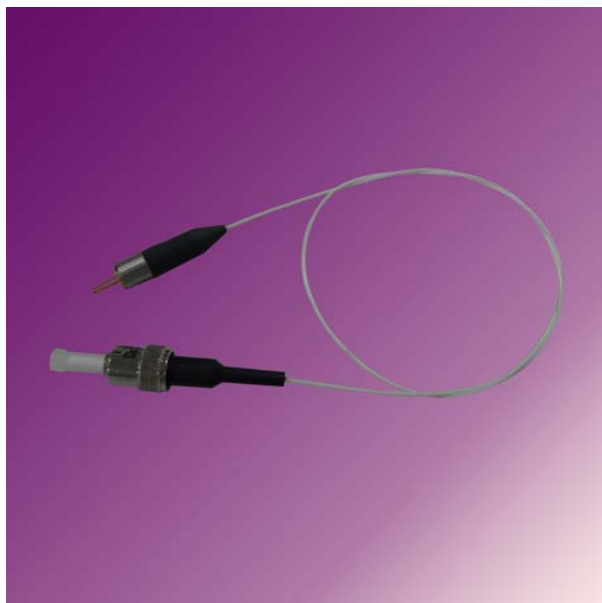
660nm Laser Diode Module (5-50mW)

G660-5mWF-03BCK-S

G660-10mWF-03BCK-S

G660-30mWF-03BCK-S

G660-50mWF-06BCK-ST



Features:

Output Power: 5mW,10mW,30mW,50mW

Wavelength: 660nm

Fiber core diameter: 4μm Single Model

0.13NA

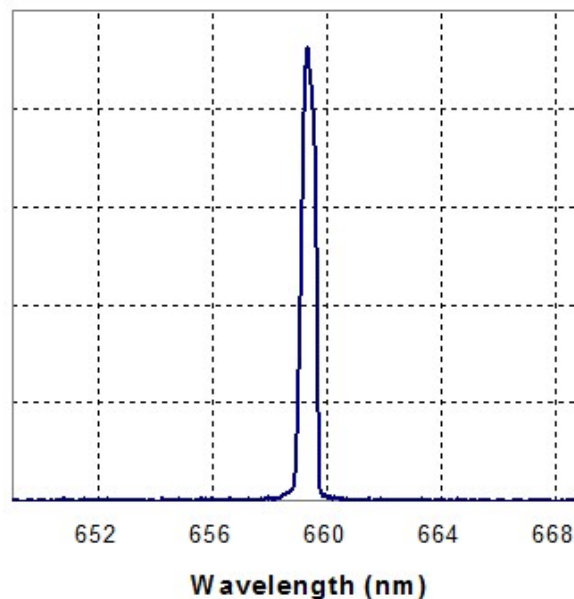
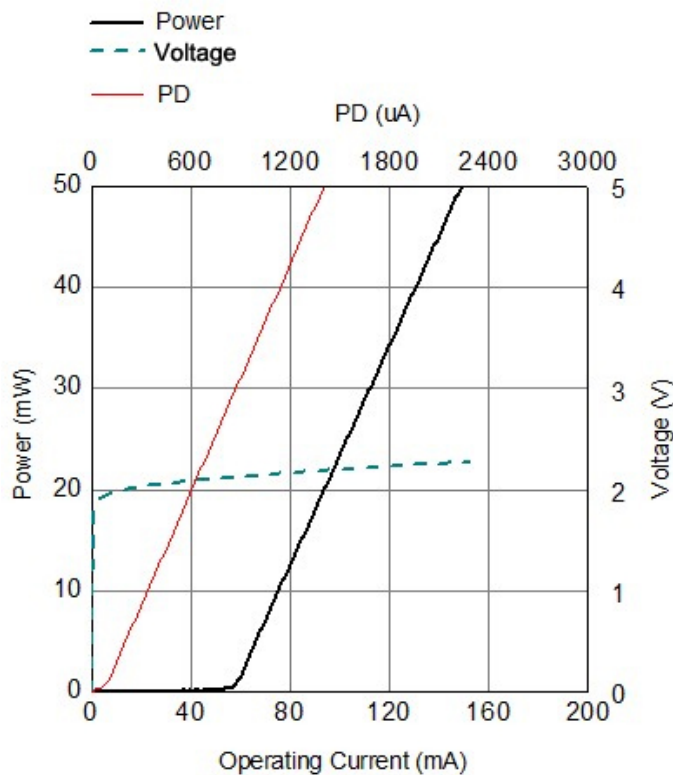
Applications

Pilot Light

Medical Use

Holography Technology

660nm Characteristics (25°C, 50mW)



Typical Device Performance (25°C)

Parameter	Symbol	Typical Value				Unit	
		G660-5mWF-03 BCK-S	G660-10mWF-03 BCK-S	G660-30mWF-03 BCK-S	G660-50mWF-06 BCK-ST		
Optical	CW Output Power	P_{op}	5	10	30	50	mW
	Center Wavelength	λ_c	660±5				nm
	Spectral Width (90% of Power)	$\Delta\lambda$	<3				nm
	Wavelength Shift with Temperature	$\Delta\lambda/\Delta T$	0.2				nm/°C
Electrical	Threshold Current	I_{th}	35	35	55	85	mA
	Operating Current	I_{op}	55	70	150	250	mA
	Operating Voltage	V_{op}	2.2-2.4				V
	TEC Max Current	I_t	-	-	-	1.8	A
	TEC Max Voltage	V_t	-	-	-	3.2	V
	Thermistor	R_t	-	-	-	10±5%/3477	(K Ω)/β (25°C)
	Slope Efficiency	η_{es}	0.3	0.3	0.3	0.3	mW /m A
Fiber	Core Diameter	d_{core}	4				μm
	Cladding Diameter	d_{clad}	125				μm
	Buffer Diameter	d_{buffer}	250				μm
	Numerical Aperture	NA	0.13				-
	Connector		FC, ST, SMA905				-

Other Parameters

Parameter	Operating Temperature /°C	Storage Temperature /°C	Storage Relative Humidity /%	Lead Soldering Temperature,10s max/°C
Min	10	-20	-	-
Max	30	80	90	250

Package Dimensions (mm)

Pin	Function
1	Laser (-)
2	Laser (+); PD N
3	PD P



Pin	Function
1	Thermistor
2	Laser (+)
3	TEC (+)
4	TEC (-)
5	Laser (-)
6	Thermistor

